### **NOTICE OF REVISION (NOR)**

(See MIL-STD-480 for instructions)

This revision described below has been authorized for the document listed.

DATE (YYMMDD)

Form Approved OMB No. 0704-0188

93-07-13

Public reporting burden for this collection is estimated to average 1 hour per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Information and Regulatory Affairs, Office of Management and Budget, Washington, DC 20503.

1. ORIGINATOR NAME AND ADDRESS	Defence Fleetrenies Cumply Center	2. CAGE CODE	3. NOR NO.	
Dayton, Ohio 45444-5277	Defense Electronics Supply Center	67268	5962-R062-93	
		4. CAGE CODE	5. DOCUMENT NO.	
		67268	82036	
6. TITLE OF DOCUMENT		7. REVISION LETTER		
MICROCIRCUITS, LINEAR, LOW OFFSET	(Current) C	(New) D		
MONOLITHIC SILICON	8. ECP NO.			
		82036ECP-1		

### 9. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES

#### 10. DESCRIPTION OF REVISION

Sheet 1: Revisions Itr column; add "D"

Revisions description column; add "Changes in accordance with

NOR 5962-R062-93"

Revisions date column: add "93-07-13".

Revision level block; add "D".

Rev status of sheets; For sheets 1, 4, 5, 10, and 11, add "D".

Sheet 4: TABLE I. Input bias current test,  $+I_{IB}$ , group A subgroups 2 and 3, device type 01, delete -3 nA min and 3 nA max and substitute -4 nA min and 4 nA max.

Revision level block; add "D".

Sheet 5: TABLE I. Output short circuit current test.

I<sub>OS(+)</sub>, group A subgroups 1 and 2, device types 01 and 02, delete -60 mA min and substitute -65 mA min. Group A subgroup 3, device types 01 and 02, delete -60 mA min and substitute -70 mA min.

I<sub>OS(-)</sub>, group A subgroups 1 and 2, device types 01 and 02, delete 50 mA max and substitute 65 mA max.

Group A subgroup 3, device types 01 and 02, delete 50 mA max and substitute 70 mA max.

Revision level block; add "D".

Sheet 10: 6.4. Approved source of supply. Under military drawing part number 8203602GX, add vendor CAGE number 27014 for vendor similar part number OP07H/883. Under military drawing part number 82036012X, delete vendor CAGE number 54186 and vendor similar part number MPOP07AL/883.

Revision level block; add "D".

CONTINUED ON NEXT SHEET

### 11. THIS SECTION FOR GOVERNMENT USE ONLY

a. CHECK ONE

[X] EXISTING DOCUMENT SUPPLEMENTED BY THIS NOR MAY BE USED IN MANUFACTURE.

RECEIVED BEFORE MANUFACTURER MAY INCORPORATE THIS CHANGE.

REVISED DOCUMENT MUST BE

[] CUSTODIAN OF MASTER DOCUMENT SHALL MAKE ABOVE REVISION AND FURNISH REVISED DOCUMENT TO:

b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT	SIGNATURE AND TITLE	DATE (YYMMDD)
DESC-ECS	MICHAEL A. FRYE BRANCH CHIEF	93-07-13
12. ACTIVITY ACCOMPLISHING REVISION	REVISION COMPLETED (Signature)	DATE (YYMMDD)
DESC-ECS	RICK C. OFFICER	93-07-13

10. DESCRIPTION OF REVISION - CONTINUED

Document No.: 82036

Revision:

NOR No.: 5962-R062-93

2 of 2

Sheet 11: 6.4. Approved source of supply - Continued. Adding vendor.

Vendor CAGE number

Vendor name and address

27014

National Semiconductor Corporation

2900 Semiconductor Drive

P.O. Box 58020

Santa Clara, CA 95052-8090

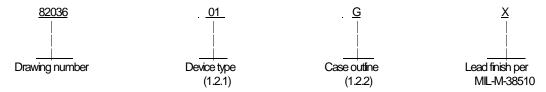
Revision level block; add "D".

									F	REVI	SION	S									 		
LTR						DE	SCRI	PTIO	٧						DATE (YR-MO-DA)				APPROVED				
В	а	and P o	case	outli	ry draw nes for AGE 3	device	type	s 01 a	nd 02	for r	new d	esign		ì	1987 JULY 24				M. A. FRYE				
С	A	Delete vendor CAGE 34371. Editorial changes throughout.  Add three vendors, CAGE 07933, CAGE 64155, and CAGE 54186.  Make changes to paragraphs 1.2.2, 4.2, and 4.3. Make changes to table I, table II, and figure 1. Editorial changes throughout.									19	989 .	JAN 2	24		M. <i>i</i>	A. FR	ΥI					
CURRE REV SHEET REV SHEET	NT			CC																			T
REV SHEET SHEET REV	NT (	RE		CC		672		C	C	C	C	C	C	C									
REV SHEET REV	TS		V		C (	C C 2 3	C C	5	C 6	C 7	8	9	10	11 <b>E E</b> L		TRO					EN	TER	
REV SHEET SHEET REV STATUS OF SHEET PMIC N/A	TS A	RE'SHI	V EET	Γ	C 1	C C 2 3	C C 4	5 cer			8	9	10	11 <b>E E</b> L		TRO					EN	TER	
REV SHEET REV SHEET REV STATUS OF SHEET MIL MIL DR	TS A DAF LITA AW	RE'SHI	V EET	Γ <b>D</b>	C 1 PREI	C C C 2 3	BY A BY J. John	5 cer		7 	8 DI	9 EFE	10	11 <b>E EL D</b> /	LINE		, <b>O</b> H	HIO OFF	<b>45</b> 4	444			
REV SHEET REV SHEET REV STATUS OF SHEE	TS A DAF LITA AW VING IS ALL D ENCIE	REY SHI	V EET	Γ D	C 1 PREI	C C C C C C C C C C C C C C C C C C C	BY J. John BY Dael A.	5 cer	6	7     N   A	8 DI	9 EFE	NSE	11 <b>E EL D</b> /	LINE	AR, L	, <b>O</b> H	HIO OFF	<b>45</b> 4	<b>444</b> г ор	\TIO		

			_
4		SCOP	ı
	١.	$\infty$	г

1.1 <u>Scope</u>. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 <u>Device types</u>. The device types shall identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
. 01	OP-07A	Operational amplifier, ultra low offset
02	OP-07	Operational amplifier, low offset

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-IM-38510, and as follows:

<u>Outline letter</u>	<u>Case outline</u>
G	A-1 (8-lead, .370" x .185"), can
Р	D-4 (8-lead, .405" x .310" x .200"), dual-in-line package
2	C-2 (20-terminal, .358" x .358" x .100"), square chip carrier
	package

1.3 Absolute maximum ratings.

1.4 Recommended operating conditions.

Supply voltage range (V <sub>CC</sub> )	±5.0 V dc to ±20.0 V dc
Ambient operating temperature range $(T_A)$	55°C to +125°C

 $<sup>\</sup>overline{1/}$  Output may be shorted to ground indefinitely at  $V_S = \pm 15 \text{ V}$ ,  $T_A = +25^{\circ}\text{C}$ . Temperature and supply voltages must be limited to ensure dissipation rating is not exceeded.

 $\underline{2}$ / Must withstand the added P<sub>D</sub> due to short circuit test, e.g., I<sub>OS</sub>

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 2

### 2. APPLICABLE DOCUMENTS

2.1 <u>Government specification and standard</u>. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

**SPECIFICATION** 

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

**STANDARD** 

MILITARY

MIL-STD-883

- Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
  - 3. REQUIREMENTS
- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
  - 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
  - 3.2.1 Terminal connections and logic diagrams. The terminal connections and logic diagrams shall be as specified on figure 1.
  - 3.2.2 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 3

### TABLE I. Electrical performance characteristics.

<b>-</b> .		Conditions $-55^{\circ}\text{C} \leq \text{T}_{A} \leq +125^{\circ}\text{C}$ $\text{V}_{CC} = \pm 15 \text{ V, unnulled,}$ $\text{V}_{CM} = 0$ (unless otherwise specified)		<u> </u>	_			
Test Sym	Symbol		Group A subgroups	Min	01    Max	Min	02    Max	Unit
Input offset voltage	V <sub>IO</sub>	1/2/	1	-25	25	-75	75	μV
		2	2,3	-60	60	-200	200	μV
Input offset voltage temperature sensitivity	dV <sub>IO</sub>	<u>3</u> /	2,3	6	i.6	-1.3	1.3	  μ <b>V/</b> °C
Input bias current	+I <sub>IB</sub>		1	-2	2	-3	3	nA
Controlle			2,3	-3	3	-6	6	nA
	-I <sub>IB</sub>		1	-2	2	-3	3	nA
			2,3	-4	4	-6	6	nA
Input offset current	+l <sub>IO</sub>		1	-2	2	-2.8	2.8	nA
			2,3	-4	4	-5.6	5.6	nA
Power supply rejection ratio	+PSRR	$V_{CC}$ + = 20 V to 5 V, $V_{CC}$ - = -15 V	1		10		10	μ <b>V/V</b>
	-PSRR	$V_{CC}$ + = 15 V, $V_{CC}$ - = -20 V to -5 V	1		10		10	  μ <b>V/V</b> 
	+PSRR	$V_{CC}$ + = 20 V to 5 V, $V_{CC}$ = -15 V	2,3		20		20	μ <b>V/V</b>
	-PSRR	$V_{CC}$ + = 15 V, $V_{CC}$ - = -20 V to -5 V	2,3		20		20	μ <b>V/V</b>

See footnotes at end of table.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 4

### TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test				Limits				
	Symbol		Group A	01		02		Unit
			subgroups	Min	Max	Min	Max	
Common mode rejection	CMRR	  V <sub>CM</sub> =±10 V	1	110		110		dB
ratio		  V <sub>CM</sub> =±13 V	2,3	106		106		dB
Output short circuit current	l <sub>OS(+)</sub>	  t≤25 ms <u>4</u> / -	1,2,3	-60	   	-60	   	mA
	los(-)		1,2,3		50		50	mA
Supply current	lcc		1		4		4	mA
			2,3		5		5	mA
Output voltage swing (minimum)	V <sub>OP</sub>	$R_L = 1 k\Omega$	4, 5, 6	-10	10	-10	10	V
		$R_L = 2000\Omega$	4, 5, 6	-12	12	-12	12	V
Open loop voltage gain (single ended)	A <sub>VS</sub>	T <sub>A</sub> =+25°C <u>5</u> /	4	300	   	200	   	V/mV
		<u>5</u> /	5, 6	200		150		V/mV

<sup>1/</sup> Users are cautioned to use the group C end-point limits for design purposes due to drift experienced with this parameter during steady-life test (see table

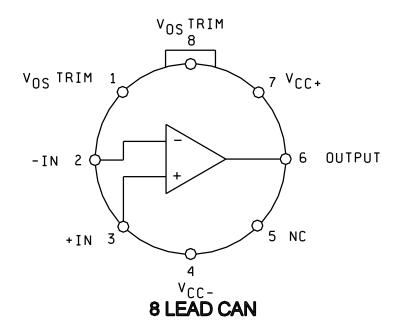
- 2/ Testing will occur at least 250 ms after application of power.
- 3/ Shall be guaranteed if not tested, to the specified parameters.
- 4/ Continuous short circuit limits are considerably less than the indicated test limits since maximum power dissipation cannot be exceeded.
- $\frac{1}{5}$  V<sub>OLIT</sub> = 0 V to +10 V for A<sub>V/S</sub>(+) and V<sub>OLIT</sub> = 0 to -10 for A<sub>V/S</sub>(-). R<sub>I</sub> = 2000 $\Omega$ .

3.6 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 5

<sup>3.5 &</sup>lt;u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

### CASE G



## CASE P

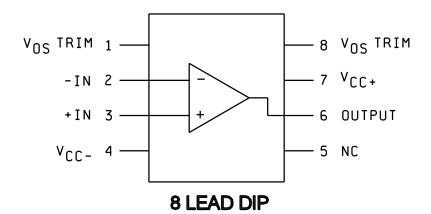


FIGURE 1. Terminal connections and logic digrams.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 6

# CASE 2

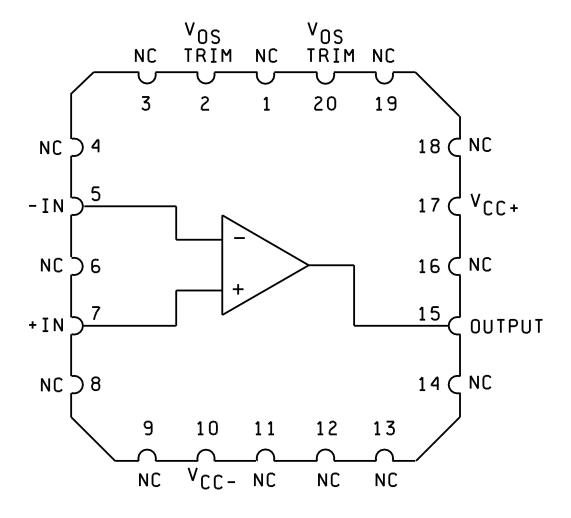


FIGURE 1. <u>Terminal connections and logic diagrams</u> - Continued.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 7

- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
    - (2)  $T_A = +125^{\circ}C$ , minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
- 4.3.1 Group A inspection.
  - a. Tests shall be as specified in table II herein.
  - b. Subgroups 7, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
- 4.3.2 Groups C and D inspections.
  - a. End-point electrical parameters shall be as specified in table II herein.
  - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
    - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
    - (2)  $T_A = +125^{\circ}C$ , minimum.
    - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET 8

### TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups   (per method   5005, table I)
Interim electrical parameters _ (method 5004)	1
  Final electrical test parameters   (method 5004)	1*, 2, 3, 4
Group A test requirements (method 5005)	1, 2, 3, 4, 5, 6
Groups C and D end-point electrical parameters (method 5005)	1** and table III

TABLE III. Group C end-point electrical parameters.

	$T_A = +25^{\circ} C, \pm V_{CC} = \pm 15 V, V_{CM} = 0 V$								
	Device 01 Device 02								
Test	End-po	int limit	De	lta	End po	int limit	Delta		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>IO</sub>	-100	+100	  -75	75	-175	+175	-100	100	   μ <b>V</b>
±lB	-3	+3	-1	1	-4.5	+4.5	1.5	1.5	nA

### 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-IM-38510.

### 6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET

82036

9

 $<sup>^*</sup>$  PDA applies to subgroup 1 excluding  $\rm V_{IO}$  \*\* Table III limits used for  $\rm V_{IO}$  and  $\rm \pm I_{IB}$  in place of table I limits.

- 6.2 Replaceability. Replaceability is determined as follows:
  - a. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
  - b. When a QPL source is established, the part numbered device specified in this drawing will be replaced by the microcircuit identified as part number M38510/13501BXX and M38510/13502BXX.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 <u>Approved source of supply</u>. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor   similar part   number <u>1</u> /	Replacement military specification part number
   8203601GX <u>2</u> /	06665 07933 64155 54186	0P07AJ 0P-07AT/883B 0P-07AH/883 MPOPO7AJ/883	M38510/13501BGX
8203601PX <u>2</u> /	06665 07933 64155 54186	0P07AZ 0P-07ADE/883B 0P-07AJ8/883 MPOPO7AZ/883	M38510/13501BPX
82036012X	06665 54186	0P07ARC MPOPO7AL/883	   M38510/13501B2X
8203602GX <u>2</u> /	06665 07933 64155 54186	0P07J 0P-07T/883B 0P-07H/883 MPOPO7J/883	M38510/13502BGX
8203602PX <u>2</u> /	06665 07933 64155 54186	0P07Z 0P-07DE/883B 0P-07J8/883 MPOPO7Z/883	M38510/13502BPX
82036022X	06665 54186	0P07RC MP0P07L/883	M38510/13502B2X

<sup>1/</sup> Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

2/ Inactive for new design, use QPL M38510 product.

STANDARDIZED MICROCIRCUIT DRAWING	SIZE <b>A</b>		82036
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL C	SHEET <b>10</b>

Vendor CAGE Vendor name number and address 06665 Precision Monolithic Incorporated 1500 Space Park Drive Santa Clara, CA 95050 07933 Raytheon Company Semiconductor Division 350 Ellis Street P.O Box 7016 Mountain View, CA 94036-7016 Linear Technology Corporation 1630 McCarthy Boulevard 64155 Milptas, CA 95035-7487 Micro Power Systems 54186 3100 Alfred Street Santa Clara, CA 95054

STANDARDIZED

MICROCIRCUIT DRAWING

DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE
A

REVISION LEVEL
C
SHEET
11